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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/545,785	04/07/2000	Tirdad Sowlati	US 000099	2253	
75	90 10/18/2002				
John C Fox c/o U S Philips Corporation Intellectual Property Department 580 White Plains Road			EXAMI	EXAMINER	
			NADAV, ORI		
Tarrytown, NY			ART UNIT	PAPER NUMBER	
			2811	12	
			DATE MAILED: 10/18/2002	DATE MAILED: 10/18/2002	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Applicati n N .	Applicant(s)			
	09/545,785	SOWLATI ET AL.			
Office Action Summary	Examiner	Art Unit			
	ori nadav	2811			
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Peri d for Reply					
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.  - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.  - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).  - Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).					
Status  1)⊠ Responsive to communication(s) filed on <u>22 J</u>	ulv 2002				
	s action is non-final.				
, <u> </u>		resocution as to the merits is			
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.  Disposition of Claims					
4)⊠ Claim(s) 1-12 is/are pending in the application.					
4a) Of the above claim(s) is/are withdrawn from consideration.					
5) Claim(s) is/are allowed.					
6)⊠ Claim(s) <u>1-12</u> is/are rejected.					
7) Claim(s) is/are objected to.					
8) Claim(s) are subject to restriction and/or	election requirement.				
Application Papers					
9)☐ The specification is objected to by the Examiner.					
10)⊠ The drawing(s) filed on <u>07 April 2000</u> is/are: a)□ accepted or b)⊠ objected to by the Examiner.					
Applicant may not request that any objection to the		• • •			
11)⊠ The proposed drawing correction filed on <u>23 <i>April</i> 2002</u> is: a)⊠ approved b)⊡ disapproved by the Examiner.					
If approved, corrected drawings are required in reply to this Office action.					
12)☐ The oath or declaration is objected to by the Examiner.					
Priority under 35 U.S.C. §§ 119 and 120					
13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).					
a) ☐ All b) ☐ Some * c) ☐ None of:					
1. Certified copies of the priority documents have been received.					
2. Certified copies of the priority documents have been received in Application No					
<ul> <li>3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).</li> <li>* See the attached detailed Office action for a list of the certified copies not received.</li> </ul>					
14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).					
a) The translation of the foreign language provisional application has been received.					
15) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.  Attachment(s)					
1) Notice of References Cited (PTO-892)  4) Interview Summary (PTO-413) Paper No(s)					
2) Notice of References Cited (PTO-692)  Notice of Draftsperson's Patent Drawing Review (PTO-948)  Information Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of Informal	Patent Application (PTO-152)			

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### **DETAILED ACTION**

1. The examiner agrees with applicant's argument that the office actions of 1/23/2002 and 4/9/2002 were directed to duplicate amendments filed on 11/9/2001 and on 2/12/2002. Therefore, the request for reconsideration of the finality of the rejection of the last Office action is valid and the finality of that action is withdrawn.

## **Drawings**

- 2. The corrected or substitute drawings were received on 4/23/2002. These drawings are approved by the examiner.
- 3. The drawings are objected to under 37 CFR 1.83(a). The drawings must show every feature of the invention specified in the claims. Figure 2B depicts dielectric layer comprising vacuum. Therefore, a silicon oxide dielectric layer must be shown or the feature(s) canceled from the claim(s). No new matter should be entered.

### Claim Rejections - 35 USC § 103

- 4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and

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the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which the subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

5. Claims 1-12 are rejected under 35 U.S.C. 103(a) as being unpatentable over Ng et al. (5,583,359) for reasons of record, as recited in previous office action (paper 10). Ng et al. teach in figure 8 a capacitor 200 over a substrate 202 comprising a first level 210 of at least four electrically conductive parallel lines extending in a first direction and lying in a first plane, at least a second level 212 comprising metal or polysilicon (column 9, lines 65-66) of at least four electrically conductive parallel lines extending in the first direction and lying in a second plane above the first plane, each of the second level lines being disposed over a respective one of the first level lines, such that the lines of the first and second levels are arranged in a series of at least four coplanar line pairs, each line pair comprising one of the first level lines and a respective one of the second level lines; a dielectric layer 250 (figure 9) disposed between the first and second levels of conductive lines; an array of vias 230 arranged such that the first level line and the second level line of each of the at least four line pairs is connected by at least a respective plurality of vias (6 vias are depicted in figure 8) thereby forming an array of at least four parallel capacitor plates, and electrically opposing nodes forming the terminals of the capacitor, the array of parallel capacitor plates electrically connected to the opposing nodes in an alternating manner so that the plates have alternating electrical polarities (figures 10-11).

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Figure 8 does not depict an array of at least four parallel capacitor plates. Figure 10 depicts a capacitor comprises plurality of parallel capacitor plates (fingers) of alternating polarity. It would have been obvious to a person of ordinary skill in the art at the time the invention was made to use an array of at least four parallel capacitor plates in Ng et al.'s device, in order to adjust the capacitance of the device according to the requirements of the application in hand.

Regarding claim 4, it would have been obvious to a person of ordinary skill in the art at the time the invention was made to use a dielectric layer comprising silicon dioxide in Ng et al.'s device, because silicon dioxide is a conventional dielectric material, of which judicial notice may be taken.

Regarding claims 5 and 6, Ng et al. teach in figure 8 at least a third level 214 of at least four electrically conductive parallel lines extending in the first direction and lying in a third plane above the first and second planes such that each of the third level lines is coplanar with a respective one of the line pairs, and a second dielectric layer 252 (figure 9) disposed between the second and third levels of conductive lines so that the third level of lines vertically extends the array of at least four parallel capacitor plates.

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Regarding claims 8-11, Ng et al. teach a capacitor being formed using known CMOS techniques (column 2, lines 56-57). Therefore, the capacitor comprises a sub-micron CMOS structure, as claimed.

Regarding claim 12, et al. teach in figure 8 a plurality of vias 230 arranged opposite a next respective plurality of vias, with identical spacing of vias in each plurality of vias.

## Response to Arguments

6. Applicant argues that figure 2B does not depict vacuum, and applicant is not required to use hash marks to signify a solid material.

The examiner does not require applicant to use hash marks to signify the silicon oxide. However, figure 2B depicts dielectric layers 27, 28 and 29. The inner walls of blocks 27, 28 and 29 are clearly visible. If dielectric layers 27, 28 and 29 comprised silicon oxide, the inner walls would not be visible. The only way the inner walls can be visible is if blocks 27, 28 and 29 comprise vacuum.

7. Applicant argues that Ng et al. do not teach a first level line and a second level line of each of the at least four line pairs is connected by at least plurality of vias.

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Figure 8 of Ng et al. clearly depicts the first level line and the second level line is connected by at least 6 vias 230. Therefore, Ng. et al. teach a first level line and a second level line of each of the at least four line pairs is connected by at least plurality of vias, as claimed.

#### Conclusion

8. **THIS ACTION IS MADE FINAL.** Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

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Group 2811 applications.

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Papers related to this application may be submitted to Technology center (TC) 2800 by facsimile transmission. Papers should be faxed to TC 2800 via the TC 2800 Fax center located in Crystal Plaza 4, room 4-C23. The faxing of such papers must conform with the notice published in the Official Gazette, 1096 OG 30 (November 15, 1989). The Group 2811 Fax Center number is (703) 308-7722 and 308-7724. The Group 2811 Fax Center is to be used only for papers related to

Any inquiry concerning this communication or any earlier communication from the Examiner should be directed to *Examiner Nadav* whose telephone number is **(703)** 308-8138. The Examiner is in the Office generally between the hours of 7 AM to 4 PM (Eastern Standard Time) Monday through Friday. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas, can be reached at **(703)** 308-2772.

Any inquiry of a general nature or relating to the status of this application should be directed to the **Technology Center Receptionists** whose telephone number is **308-0956** 

Ori Nadav

October 10, 2002

TOM THOMAS
SUPERVISORY PATENT EXAMINER
TECHNOLOGY CENTER 2800

1pm pound